

Vishay Semiconductors

Small Signal Schottky Diode



DESIGN SUPPORT TOOLS click logo to get started

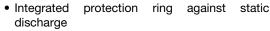


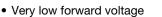
MECHANICAL DATA

Case: MicroMELF
Weight: approx. 12 mg
Cathode band color: black
Packaging codes/options:

TR3/10K per 13" reel (8 mm tape), 10K/box TR/2.5K per 7" reel (8 mm tape), 12.5K/box

FEATURES





• AEC-Q101 qualified

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

Applications where a very low forward voltage is required

PARTS TABLE					
PART TYPE DIFFERENTIATION		ORDERING CODE	CIRCUIT CONFIGURATION	REMARKS	
BAS386	V _R = 50 V	BAS386-TR3 or BAS386-TR	Single	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	50	V	
Peak forward surge current	t _p = 10 ms	I _{FSM}	5	Α	
Repetitive peak forward current	t _p ≤ 1 s	I _{FRM}	500	mA	
Forward continuous current		I _F	200	mA	
Average forward current		I _{FAV}	200	mA	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	320	K/W		
Junction temperature		T _j	125	°C		
Storage temperature range		T _{stg}	-65 to +150	°C		

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$I_F = 0.1 \text{mA}$	V _F			300	mV
	I _F = 1 mA	V _F			380	mV
Forward voltage	I _F = 10 mA	V _F			450	mV
	I _F = 30 mA	V _F			600	mV
	I _F = 100 mA	V _F			900	mV
Reserve current	V _R = 40 V	I _R			5	μA
Diode capacitance	V _R = 1 V, f = 1 MHz	C _D			8	pF

Vishay Semiconductors

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

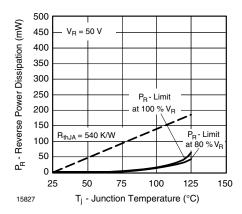


Fig. 1 - Max. Reverse Power Dissipation vs.
Junction Temperature

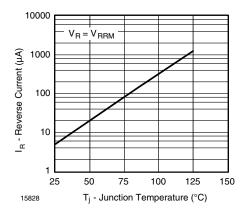


Fig. 2 - Reverse Current vs. Junction Temperature

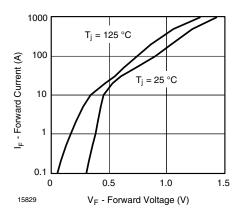


Fig. 3 - Forward Current vs. Forward Voltage

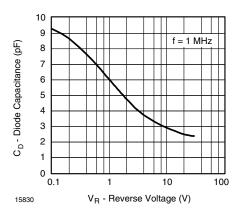


Fig. 4 - Diode Capacitance vs. Reverse Voltage

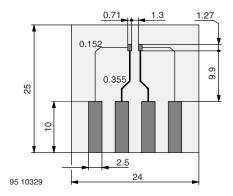
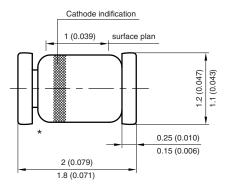


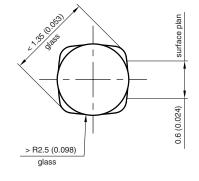
Fig. 5 - Board for R_{thJA} Definition (in mm)



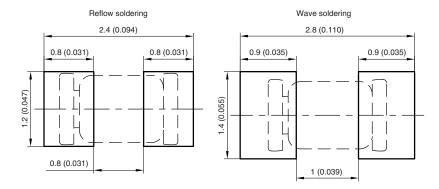
Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters (inches): MicroMELF





Foot print recommendation:



Created - Date: 26.July.1996 Rev. 13 - Date: 07.June.2006 Document no.:6.560-5007.01-4 96 12072

^{*} The gap between plug and glass can be either on cathode or anode side



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT
54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP
SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP
SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF
ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF
ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573
NTE6081